

# Product Document



## Datasheet

DS000511

# AS5715A/AS5715R

**On-/Off-Axis Inductive Position Sensor with  
Sin/Cos Output**

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# Content Guide

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# 1 General Description

The AS5715A/AS5715R is an inductive sensor IC with differential SIN/COS output for high speed position sensing applications. To fulfill its purpose, the AS5715A/AS5715R device has to be connected to a coil system. The coil system consists of a TX (transmitting) and two RX (receiving) coils typically integrated on a PCB (Printed Circuit Board). The device excites the TX coil with a high frequency voltage. A target above the coil system effects the amount of voltage induced into the RX coils depending on the position of the target. The device senses, demodulates, and amplifies this voltage. If the coil system is designed properly, then the device output delivers SIN and COS shaped voltages. An ECU (Electronic Control Unit) can calculate the target position by applying an atan2() function to the SIN and COS output signal. The AS5715A/AS5715R is defined as SEooC (Safety Element out of Context) according ISO26262.

## 1.1 Key Benefits & Features

The benefits and features of AS5715R, On-/Off-Axis Inductive Position Sensor with Sin/Cos Output, are listed below:

**Figure 1:**  
Added Value of Using AS5715R

| Features  | Benefits   |
|---|--|
| On and off axis applications  | Flexible PCB design possible. Enabling hollow shaft and side shaft applications.     |
| Adaptable coil system layout  | Adaptable to the pole pair count of the motor  |
| Typical accuracy with 4 pole-pair configuration: <0.075 deg mechanical, <0.3 deg electrical | Low torque ripple and motor noise and increased efficiency                           |
| Suitable for high speed applications  | 3.3 $\mu$ s propagation delay and output bandwidth for applications up to 480000 rpm |
| Differential SIN and COS output   | Easy replacement of existing AMR/GMR sensors   |
| Functional safety diagnostics   | ASIL C(D) as SEooC   |
| Suitable for automotive applications  | AEC-Q100 Grade 0 qualified up to -40 °C to 160 °C                                    |

## 1.2 Applications

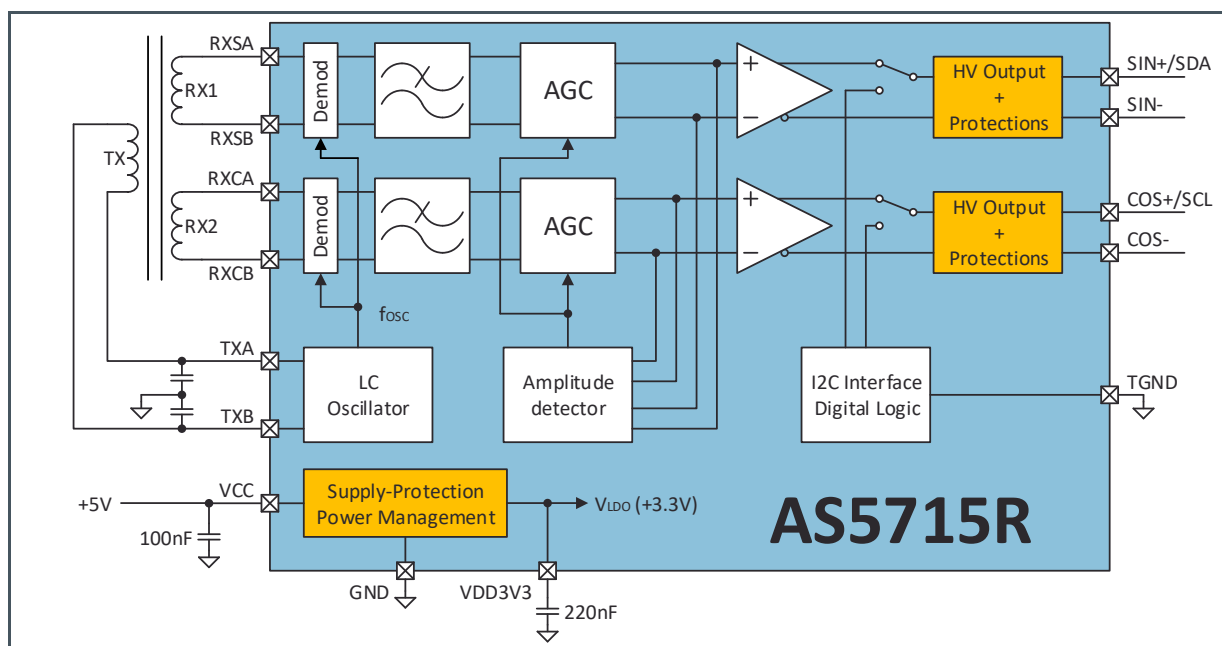
- BLDC motor control
- Traction motors for electric vehicles
- Electric power steering

- Brake boosters
- Replacement of expensive and bulky resolvers
- Mirror LIDAR and closed loop servo motor systems

## 1.3 Block Diagram

The functional blocks of this device are shown below:

**Figure 2:**  
**Functional Blocks of AS5715R**



## 2 Ordering Information

| Ordering Code | Package  | Marking | Delivery Form | Delivery Quantity |
|---------------|----------|---------|---------------|-------------------|
| AS5715R-ZTST  | TSSOP-14 | AS5715R | Tape & Reel   | 4500 pcs/reel     |
| AS5715R-ZTSM  | TSSOP-14 | AS5715R | Tape & Reel   | 500 pcs/reel      |
| AS5715A-ZTST  | TSSOP-14 | AS5715A | Tape & Reel   | 4500 pcs/reel     |
| AS5715A-ZTSM  | TSSOP-14 | AS5715A | Tape & Reel   | 500 pcs/reel      |

The AS5715A is a preprogrammed derivative of the AS5715R. This means that the AS5715A is not programmable. The table below shows how the registers of the AS5715A are programmed:

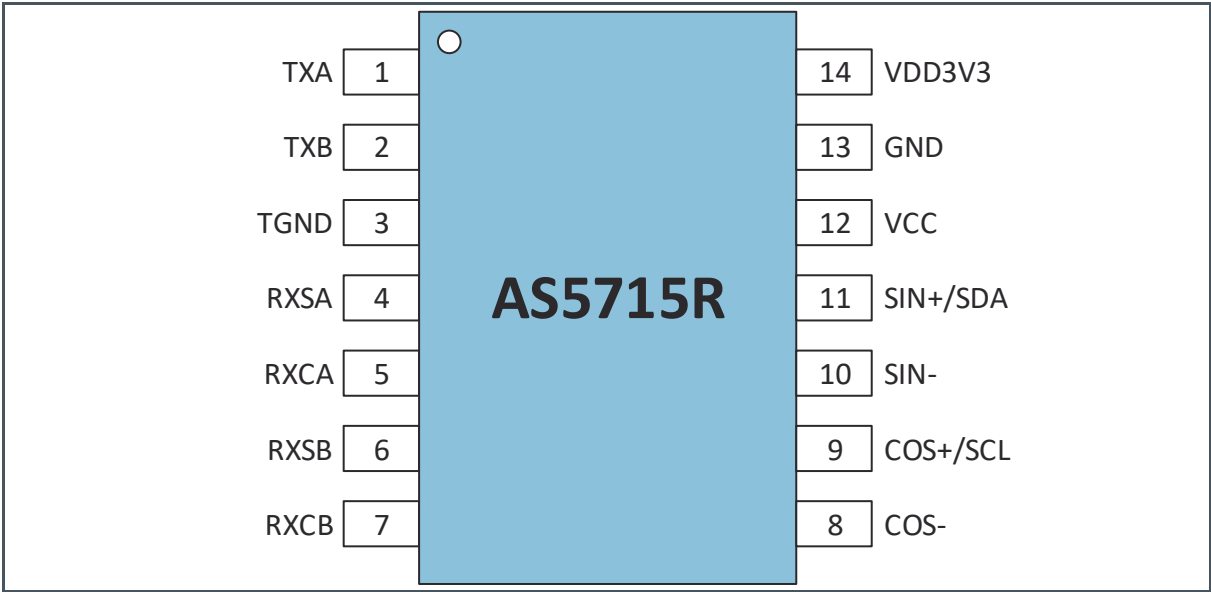
| Register | Content |
|----------|---------|
| 1Dh      | C0h     |
| 1Eh      | D0h     |

The tolerance of the preprogrammed AS5715A gain factor is  $\pm 1\text{dB}$ .

### 3 Pin Assignment

#### 3.1 Pin Diagram

Figure 3:  
TSSOP-14 Pin Assignment



## 3.2 Pin Description

Figure 4:  
Pin Description of AS5715R (TSSOP14)

| Pin Number | Pin Name | Pin Type <sup>(1)</sup> | Description   | Comments  |
|------------|----------|-------------------------|---|---|
| 1          | TXA      | AO                      | 1 <sup>st</sup> side of transmit coil connection        |   |
| 2          | TXB      | AO                      | 2 <sup>nd</sup> side of transmit coil connection        |   |
| 3          | TGND     | DI                      | TEST pin  | Connect either to GND or VDD3V3 in normal operation |
| 4          | RXSA     | AI                      | SIN channel RX input                                    |   |
| 5          | RXCA     | AI                      | COS channel RX input                                    |   |
| 6          | RXSB     | AI                      | SIN channel RX input                                    |   |
| 7          | RXCB     | AI                      | COS channel RX input                                    |   |
| 8          | COS-     | AO                      | Inverting COS output                                    |   |
| 9          | COS+/SCL | AO (DI)                 | Non inverting COS output (SCL in I <sup>2</sup> C mode) |   |
| 10         | SIN-     | AO                      | Inverting SIN output                                    |   |
| 11         | SIN+/SDA | AO (DIO)                | Non inverting SIN output (SDA in I <sup>2</sup> C mode) |   |
| 12         | VCC      | S                       | Input for 5 V Power supply operation                    |   |
| 13         | GND      | S                       | Reference GND   |   |
| 14         | VDD3V3   | AO                      | Output of internal LDO                                  |   |

- (1) Explanation of abbreviations:
- DI Digital Input
  - DIO Digital Input/Output
  - AI Analog Input
  - AO Analog Output
  - S Supply Pin



## 4 Absolute Maximum Ratings

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated under “Operating Conditions” is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Figure 5:**  
**Absolute Maximum Ratings of AS5715R**

| Symbol   | Parameter                                    | Min    | Max | Unit | Comments  |
|--|--|--------|-----|------|---|
| Electrical Parameters                                  |  |        |     |      |   |
| V <sub>CC</sub>  | Supply Voltage to Ground                     | -20    | 20  | V    | Applicable for pin VCC                            |
| V <sub>OUT</sub>                                       | Output Pin Voltage to GND                    | -0.3   | 20  | V    | Applicable for pins COS+, COS-, SIN+, SIN-        |
| V <sub>LDO</sub>                                       | Output Pin Voltage to GND                    | -0.3   | 5.0 | V    | Applicable for pin VDD3V3                         |
| V <sub>TX</sub>  | Output Pin Voltage to GND                    | -0.3   | 3.6 | V    | Applicable for pin TXA, TXB                       |
| V <sub>RX</sub>  | Input Pin Voltage to GND                     | -0.3   | 3.6 | V    | Applicable for pin RXSA, RXSB, RXCA, RXCB         |
| I <sub>SCR</sub>                                       | Input Current (latch-up immunity)            | ± 100  |     | mA   | AEC-Q100-004                                      |
| Continuous Power Dissipation (T <sub>A</sub> = 160 °C) |  |        |     |      |   |
| P <sub>T</sub>   | Continuous Power Dissipation                 | 112    |     | mW   |   |
| Electrostatic Discharge                                |  |        |     |      |   |
| ESD <sub>HBM</sub> on Chip level                       | Electrostatic Discharge Human Body Model     | ± 4000 |     | V    | AEC-Q100-002                                      |
| ESD <sub>MM</sub> on Chip level                        | Electrostatic Discharge Machine Model        | ± 150  |     | V    | AEC-Q100-003                                      |
| ESD <sub>CDM</sub> on Chip level                       | Electrostatic Discharge Charged Device Model | ± 500  |     | V    | AEC-Q100-011                                      |
| ESDC <sub>CDM</sub> on Chip level                      | Electrostatic Discharge CDM on corner pins   | ± 750  |     | V    | AEC-Q100-011                                      |
| Temperature Ranges and Storage Conditions              |  |        |     |      |   |
| T <sub>A</sub>   | Operating Ambient Temperature                | -40    | 160 | °C   |   |
| R <sub>THJA</sub>                                      | Junction to Ambient Thermal Resistance       |        | 89  | °C/W |   |
| T <sub>J</sub>   | Operating Junction Temperature               |        | 170 | °C   |   |
| T <sub>STRG</sub>                                      | Storage Temperature Range                    | -55    | 125 | °C   | 150 °C for 1000 h                                 |
| T <sub>BODY</sub>                                      | Package Body Temperature                     |        | 260 | °C   | IPC/JEDEC J-STD-020E <sup>(1)</sup>               |
| R <sub>HNC</sub>                                       | Relative Humidity (non-condensing)           | 5      | 85  | %    |   |
| MSL  | Moisture Sensitivity Level                   | 3      |     |      | Represents a maximum floor life time of 168 hours |

| Symbol                            | Parameter                        | Min  | Max | Unit | Comments                |
|-----------------------------------|----------------------------------|------|-----|------|-------------------------|
| Lifetime and Temperature Profiles |                                  |      |     |      |                         |
| t <sub>OP_160</sub>               | Cumulative duration in operation | 1500 |     | h    | T <sub>A</sub> = 160 °C |

- (1) The reflow peak soldering temperature (body temperature) is specified according to IPC/JEDEC J-STD-020E “Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices.” The lead finish for Pb-free leaded packages is “Matte Tin” (100% Sn)

# 5 Electrical Characteristics

All limits are guaranteed. The parameters with Min and Max values are guaranteed with production tests or SQC (Statistical Quality Control) methods.

All in this datasheet defined tolerances for external components need to be assured over the whole operation conditions range and also over lifetime.

Overall condition:  $T_A = -40\text{ }^{\circ}\text{C}$  to  $160\text{ }^{\circ}\text{C}$ ,  $V_{CC} = 4.5\text{ V}$  to  $5.5\text{ V}$ ; components specification; unless otherwise noted.

## 5.1 Power Supply

Figure 6:  
Power Supply

| Symbol                | Parameter   | Conditions   | Min | Typ | Max | Unit |
|-----------------------|---|--|-----|-----|-----|------|
| VCC                   | Guaranteed positive supply voltage with regulator in use            | Beyond that the chip may go into safe state within the $V_{CC_{OVT}}/V_{CC_{UVT}}$ ranges but will continue to work in spec up until that thresholds (no grey zones) | 4.5 | 5.0 | 5.5 | V    |
| t <sub>VCC_RISE</sub> | VCC supply rise time, rise time has to be higher than specified Min | Guaranteed by design   | 100 |     |     | ns   |
| ICC                   | Supply current  | Without output current and $Q_{TX} = 40$   | 5   | 10  | 12  | mA   |
|                       |   | Without output current and $Q_{TX} = 8$ , (guaranteed by design)   | 5   |     | 15  | mA   |
| t <sub>START</sub>    | Start-up time   | Functional mode (guaranteed by design)   |     |     | 3   | ms   |

## 5.2 Analog Signal Chain

**Figure 7:**  
Analog Signal Chain

| Symbol                   | Parameter   | Conditions   | Min | Typ  | Max | Unit     |
|--------------------------|---|--|-----|------|-----|----------|
| $V_{RX}$                 | Input Level on all RX pins  | Information parameter (guaranteed by design)               | 5   |      | 200 | mVpp     |
| $n_{RX}$                 | Differential noise on input   | 10kHz to 30 kHz (guaranteed by design)                     |     |      | 1   | Vpp      |
| $RX\_ERR^{(1)}$          | Overall electrical angular error of RX channels                                 | With offset compensation in the ECU (guaranteed by design) |     |      | 1   | °        |
| $RX\_ERR_{UNCOMP}^{(2)}$ | Overall electrical angular error of RX channels                                 | Without offset and gain compensation                       |     |      | 4   | °        |
| $INL_{RX}$               | Gain linearity of RX channel  | Guaranteed by design                                       |     |      | 1   | %        |
| Delay_error              | Phase shift between the SIN and COS channel at $f_{IN} = 8$ kHz                 |  |     |      | 0.3 | °        |
| $f_{IN}^{(3)}$           | Frequency of the signal AM modulated to the LC oscillators frequency $f_{TX}$ . |  | 0   |      | 8   | kHz      |
| $t_{PROPDELAY}$          | Propagation delay   | SC_filter enabled (guaranteed by design)                   | 3.5 | 4.65 | 5.8 | µs       |
|                          |   | SC_filter disabled (guaranteed by design)                  | 2   | 2.65 | 3.3 | µs       |
| $AGC_{GAIN\_H}$          | Gain factor high  |  | 49  |      |     | dB       |
| $AGC_{GAIN\_L}$          | Gain factor low   |  |     |      | 27  | dB       |
| $V_{AGC\_REG\_L}$        | AGC low level regulation threshold for p-p signal                               | Default configuration<br>AGC_cmp_high_thr = 0              | 32  | 35   | 38  | % of VCC |
|                          |   | Extended configuration<br>AGC_cmp_high_thr = 1             | 45  | 48.5 | 52  | % of VCC |
| $V_{AGC\_REG\_H}$        | AGC high level regulation threshold for p-p signal                              | Default configuration<br>AGC_cmp_high_thr = 0              | 66  | 70   | 74  | % of VCC |
|                          |   | Extended configuration<br>AGC_cmp_high_thr = 1             | 91  | 95   | 99  | % of VCC |
| $AGC_{STEP\_REG}$        | AGC regulation gain factor  | When $V_{AGC\_REG}$ threshold is reached                   |     | 0.25 |     | dB       |
| $t_{REG}$                | Regulation wait time  |  |     | 25   |     | µs       |
| $V_{AGC\_LIMIT\_L}$      | AGC zero crossing threshold for p-p signal                                      | Default configuration<br>AGC_cmp_high_thr = 0              | 6   | 9    | 12  | % of VCC |
|                          |   | Extended configuration<br>AGC_cmp_high_thr = 1             | 9   | 12   | 16  | % of VCC |
| $V_{AGC\_LIMIT\_H}$      | AGC high level clipping threshold for p-p signal                                | Default configuration<br>AGC_cmp_high_thr = 0              | 86  | 90   | 93  | % of VCC |

| Symbol                    | Parameter   | Conditions                                       | Min | Typ | Max | Unit     |
|---------------------------|---|--|-----|-----|-----|----------|
|                           |   | Extended configuration<br>AGC_cmp_high_thr = 1   | 118 | 122 | 126 | % of VCC |
| AGC <sub>STEP_LIMIT</sub> | AGC step gain factor step                         | When V <sub>AGC_LIMIT</sub> threshold is reached |     | 3   |     | dB       |
| t <sub>LIMIT</sub>        | Step wait time                                    |  |     | 3   |     | µs       |
| gain <sub>mm</sub>        | Overall gain mismatch between SIN and COS channel | Guaranteed by design                             |     |     | 2   | %        |

- (1) This error includes noise and gain mismatch as main error contributor but also errors caused by other effects. The error caused by noise can be decreased by an input signal with higher amplitude. The error caused by gain mismatch can be reduced by gain error compensation in the ECU. Guaranteed between 10% to 90% of VCC peak to peak differential output.
- (2) The parameter RX\_ERR<sub>UNCOMP</sub> specifies the overall uncompensated angular error produced by the IC only, assuming ideal RX input signals. This parameter includes INL<sub>RX</sub>, Delay\_error, V<sub>OFFSET\_RX</sub>, OPN and gain<sub>mm</sub>.
- (3) Typical calculation:  $f_{IN} = (\text{rotation\_speed\_in\_rpm} / 60) * \text{num\_of\_pole\_pairs}$

## 5.3 LC - Oscillator

**Figure 8:**  
**LC - Oscillator**

| Symbol                   | Parameter   | Conditions   | Min | Typ | Max  | Unit |
|--------------------------|---|--|-----|-----|------|------|
| V <sub>TX</sub>          | Coil driving voltage                                |  | 2.0 | 2.5 | 3.0  | Vpp  |
| f <sub>TX</sub>          | Dependent on resonant frequency of external LC Tank |  | 2.8 |     | 5    | MHz  |
| f <sub>DET_WD_low</sub>  | Lower LC frequency error detection level            |  | 2.4 | 2.6 | 2.8  | MHz  |
| f <sub>DET_WD_high</sub> | Upper LC frequency error detection level            | Default configuration<br>LC_wide_range = 0                         | 5   | 5.5 | 6    | MHz  |
|                          |   | Extended configuration<br>LC_wide_range = 1                        | 6.9 | 7.5 | 8.1  | MHz  |
| t <sub>DET_WD</sub>      | Watch dog error detection time                      | Time it takes to detect if LC oscillator is out of frequency-range |     | 500 | 1000 | µs   |
| THD <sub>TX</sub>        | Harmonic content of TX signal                       |  |     |     | -30  | dB   |

## 5.4 Analog Output

**Figure 9:**  
Analog Output

| Symbol                                | Parameter   | Conditions  | Min  | Typ | Max  | Unit     |
|---------------------------------------|---|---|------|-----|------|----------|
| OP                                    | Output common mode operating point                                    |   | 48   | 50  | 52   | % of VCC |
| OP <sub>DIFF</sub>                    | OP difference between channels  |   |      |     | 2.5  | % of VCC |
| CM <sub>TH</sub>                      | OP comparator threshold, triggers SM8 if exceeded                     | Comparison of differential output common mode voltage against 50% of VCC                    | ±100 |     | ±500 | mV       |
| OSTD                                  | OP temperature drift  | Guaranteed by design  | -1   |     | 1    | %        |
| V <sub>OFFSET_RX</sub>                | Offset of differential output signal                                  |   | -30  |     | 30   | mV       |
| OPN <sup>(1)</sup>                    | Output noise  | 10 kHz bandwidth; max AGC gain factor SC_filter enabled                                     |      | 1.5 | 1.9  | mVrms    |
|                                       |   | 10 kHz bandwidth; max AGC gain factor SC_filter disabled                                    |      | 1.9 | 2.4  | mVrms    |
|                                       |   | Unlimited bandwidth; max AGC gain factor SC_filter enabled                                  |      | 3.6 | 5    | mVrms    |
|                                       |   | Unlimited bandwidth; max AGC gain factor SC_filter disabled                                 |      | 8.5 | 11   | mVrms    |
| IOUT                                  | Output operating current capability                                   | Consists of static current (incl. external pull-up) and dynamic current for capacitive load | 3.5  |     |      | mA       |
| IOUT <sub>SCVCC</sub>                 | Output short circuit current to VCC                                   | Output pins (SIN+, SIN-, COS+, COS-) forced to VCC  | 5    | 15  | 25   | mA       |
| IOUT <sub>SCGND</sub>                 | Output short circuit current to GND                                   | Output pins (SIN+, SIN-, COS+, COS-) forced to GND  | 5    | 15  | 25   | mA       |
| VOUT <sup>(2)</sup>                   | Output voltage range  | Output pins (SIN+, SIN-, COS+, COS-) to GND   | 5    |     | 95   | % of VCC |
| IOUT <sub>HIGH-Z</sub> <sup>(3)</sup> | Output leakage current in high-Z                                      | VCC = 4.05 V, R <sub>Pu</sub> = 4 k, VOUT = 96% of VCC (SIN+, SIN-, COS+, COS-)             |      |     | 40   | µA       |
| VOUT <sub>CLAMPL</sub>                | Output level clamping low (in I <sup>2</sup> C mode or PWM safe mode) | 3 mA sinking at output pins (SIN+, SIN-, COS+, COS-)  |      |     | 10   | % of VCC |

(1) Guaranteed by design

(2) The parameter VOUT specifies the general possible output voltage range under the assumption, that the ECU is detecting a voltage level out of this range as a failureband. The final amplitude of the output voltage signal depends only on the RX input signal and the AGC gain factor and should fall into this specified range.

(3) The parameter IOUT<sub>HIGH-Z</sub> specifies the maximum output leakage current at the output pin in high-Z configuration to fulfill the 96% of VCC level, assuming minimum VCC and minimum external pull-up. In the end application, the output level clamping high depends on the external pull-up resistor (R<sub>Pu</sub>), which must be connected between each output pin and the VCC level.

The voltages  $V_{SIN+}$ ,  $V_{SIN-}$ ,  $V_{COS+}$  and  $V_{COS-}$  are measured from the pins SIN+, SIN-, COS+ and COS- to GND. OP refers to  $OP_{SIN}$  and  $OP_{COS}$ .

$$OP_{SIN} = \frac{V_{SIN+} + V_{SIN-}}{2} \approx 2.5 \text{ V}$$

$$OP_{COS} = \frac{V_{COS+} + V_{COS-}}{2} \approx 2.5 \text{ V}$$

$$OP_{SIN\%} = \frac{OP_{SIN}}{VCC} * 100 \approx 50 \% \text{ of VCC}$$

$$OP_{COS\%} = \frac{OP_{COS}}{VCC} * 100 \approx 50 \% \text{ of VCC}$$

$$OP_{SIN} \neq OP_{COS}$$

$$OP_{SIN\%} \neq OP_{COS\%}$$

$$\frac{|OP_{SIN} - OP_{COS}|}{VCC} * 100 < OP_{DIFF}$$

## 5.5 Power Management

**Figure 10:**  
Power Management

| Symbol                  | Parameter                          | Conditions   | Min  | Typ  | Max  | Unit |
|-------------------------|------------------------------------|--|------|------|------|------|
| VCC <sub>OVTH</sub>     | VCC overvoltage threshold high     | Please refer to Figure 12  | 5.65 | 5.8  | 5.95 | V    |
| VCC <sub>OVTL</sub>     | VCC overvoltage threshold low      | Please refer to Figure 12  | 5.5  | 5.65 | 5.8  | V    |
| VCC <sub>OVH</sub>      | VCC overvoltage hysteresis         | Please refer to Figure 12  | 100  | 150  | 200  | mV   |
| t <sub>VCCOVD</sub>     | VCC overvoltage detection time     | Time from VCC exceeding VCC <sub>OVTH</sub> to detection asserts<br>Please refer to Figure 12  |      | 250  | 500  | μs   |
| t <sub>VCCOVRT</sub>    | VCC overvoltage recovery time      | Time from VCC falls below VCC <sub>OVTL</sub> (recovers to VCC) to normal operation Sin/Cos Output signal<br>Please refer to Figure 12 |      | 500  | 1000 | μs   |
| VCC <sub>UVTH</sub>     | VCC undervoltage threshold high    | Please refer to Figure 12  | 4.2  | 4.35 | 4.5  | V    |
| VCC <sub>UVTL</sub>     | VCC undervoltage threshold low     | Please refer to Figure 12  | 4.05 | 4.2  | 4.35 | V    |
| VCC <sub>UVH</sub>      | VCC undervoltage hysteresis        | Please refer to Figure 12  | 100  | 150  | 200  | mV   |
| t <sub>VCCUVD</sub>     | VCC undervoltage detection time    | Time from VCC falls below VCC <sub>UVTL</sub> to detection asserts<br>Please refer to Figure 12  |      | 250  | 500  | μs   |
| t <sub>VCCUVRT</sub>    | VCC undervoltage recovery time     | Time from VCC exceeds VCC <sub>UVTH</sub> (recovers to VCC) to normal operation Sin/Cos Output signal<br>Please refer to Figure 12     |      | 500  | 1000 | μs   |
| VDD3V3 <sub>OVTH</sub>  | VDD3V3 overvoltage threshold high  |  | 3.42 | 3.53 | 3.60 | V    |
| VDD3V3 <sub>OVTL</sub>  | VDD3V3 overvoltage threshold low   |  | 3.37 | 3.41 | 3.52 | V    |
| VDD3V3 <sub>OVH</sub>   | VDD3V3 overvoltage hysteresis      |  | 30   | 50   | 70   | mV   |
| t <sub>VDD3V3OVD</sub>  | VDD3V3 overvoltage detection time  | Time from VCC exceeds VDD3V3 <sub>OVTH</sub> to detection asserts  |      | 250  | 500  | μs   |
| t <sub>VDD3V3OVRT</sub> | VDD3V3 overvoltage recovery time   | Time from VCC falls below VDD3V3 <sub>OVTL</sub> (recovers to VDD3V3) to normal operation Sin/Cos Output signal                        |      | 500  | 1000 | μs   |
| VDD3V3 <sub>UVTH</sub>  | VDD3V3 undervoltage threshold high |  | 3.07 | 3.16 | 3.23 | V    |
| VDD3V3 <sub>UVTL</sub>  | VDD3V3 undervoltage threshold low  |  | 3    | 3.07 | 3.16 | V    |
| VDD3V3 <sub>UVH</sub>   | VDD3V3 undervoltage hysteresis     |  | 30   | 50   | 70   | mV   |
| t <sub>VDD3V3UVD</sub>  | VDD3V3 undervoltage detection time | Time from VCC falls below VDD3V3 <sub>UVTL</sub> to detection asserts  |      | 250  | 500  | μs   |
| t <sub>VDD3V3UVRT</sub> | VDD3V3 undervoltage recovery time  | Time from VCC exceeds VDD3V3 <sub>UVTH</sub> (recovers to VDD3V3) to normal operation Sin/Cos Output signal                            |      | 500  | 1000 | μs   |



| Symbol    | Parameter                    | Conditions   | Min  | Typ | Max  | Unit |
|-----------|------------------------------|--|------|-----|------|------|
| $V_{LDO}$ | Internally regulated Voltage | VDD3V3 must not be loaded by any external DC current | 3.23 | 3.3 | 3.37 | V    |
| $f_{RC}$  | RC oscillator frequency      |  | 7.3  | 8   | 8.7  | MHz  |

## 5.6 Off-Chip Components

**Figure 11:**  
**Off-Chip Components**

| Symbol              | Parameter                               | Conditions  | Min  | Typ | Max  | Unit       |
|---------------------|---|---|------|-----|------|------------|
| $C_{VDD3V3}$        | Stabilization cap on VDD3V3             |   | 80   | 220 | 1100 | nF         |
| $C_{VCC}^{(2)}$     | Stabilization cap on VCC                |   | 80   | 100 |      | nF         |
| $C_{OUT}^{(1)}$     | Capacitive load on analog output pins   | Applicable for output pins (SIN+, SIN-, COS+, COS-)         | 2.2  | 4.7 | 47   | nF         |
| $L_{TX}$            | TX coil inductance                      |   | 1    |     | 20   | $\mu$ H    |
| $G_{TX}$            | TX - LC tank AC conductance             |   | 0.05 |     | 1.5  | mS         |
| $C_{LC-TANK}$       | LC tank capacitance                     | Overall capacitance of 2 series caps                        | 200  | 600 | 3000 | pF         |
| $Q_{TX}$            | TX coil quality factor                  |   | 8    | 20  | 40   |            |
| $L_{RX}$            | RX coil inductance                      |   |      |     | 4    | $\mu$ H    |
| $C_{RX\_parasitic}$ | RX coil parasitic capacitance           | Differential between input pins RXSA – RXSB and RXCA – RXCB |      |     | 20   | pF         |
| $R_{RX\_parasitic}$ | RX coil parasitic resistor              |   |      |     | 20   | $\Omega$   |
| $R_{PU}^{(1)}$      | Pull-up resistors on analog output pins | Applicable for output pins (SIN+, SIN-, COS+, COS-)         | 4    |     | 10   | k $\Omega$ |

- (1) Due to the specified output capacitor and pull-up resistor range, full I<sup>2</sup>C specification compliance is not guaranteed.
- (2) There is no max limit specified, as a higher cap value always leads to better stabilization behavior, but with increasing cap value, a longer startup time must be taken into account. After reaching the internal POR level (~2.8 V), the outputs remain per default in high-Z configuration for 3 ms. If the nominal VCC level is reached within this 3 ms, the outputs are already settled. If the startup takes longer than 3 ms, the output signals will provide immediately the SIN/COS signal according to the RX input signal multiplied with the gain factor. With active AGC regulation, where the thresholds are ratiometric to VCC, a regulation can still occur, as long as the final VCC level is not reached.



### Information

All specified tolerances for external components need to be assured over the whole operation conditions range and also over lifetime.

## 6 Functional Description

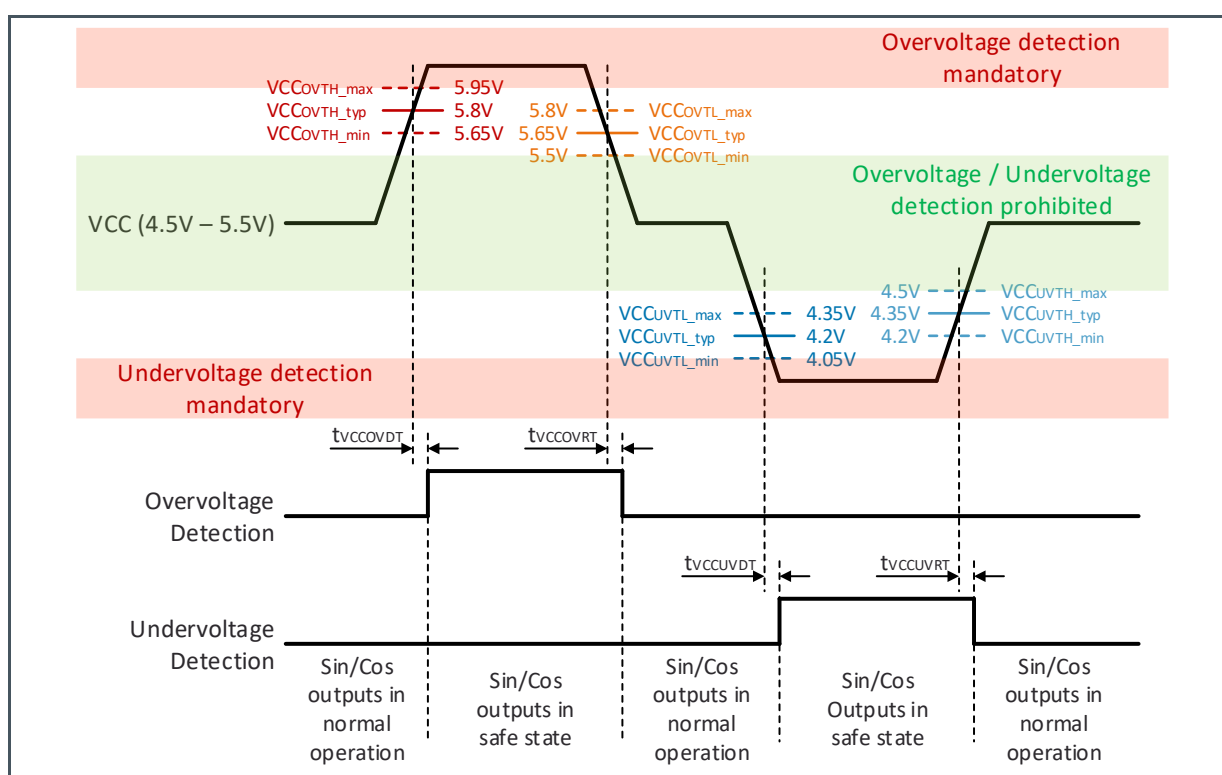
The AS5715A/AS5715R is an inductive-based rotary or linear position sensor using CMOS technology.

### 6.1 Power Supply

#### 6.1.1 5 V VCC Supply

The device has an integrated overvoltage and undervoltage detection. Figure 12 describes the transition behavior between overvoltage, undervoltage and operational mode condition. An undefined zone is not possible, the device is either in operational mode or in safe mode.

**Figure 12:**  
Reset Thresholds for 5 V VCC Supply

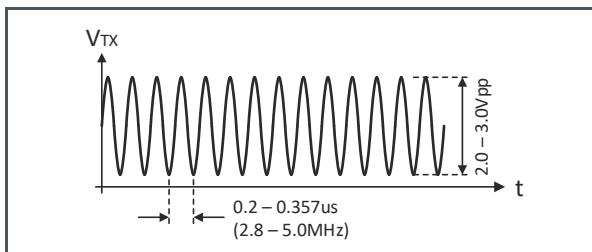


The internal LDO block regulates the 5 V supply voltage (VCC) down to a 3.3 V level ( $V_{LDO}$ ).

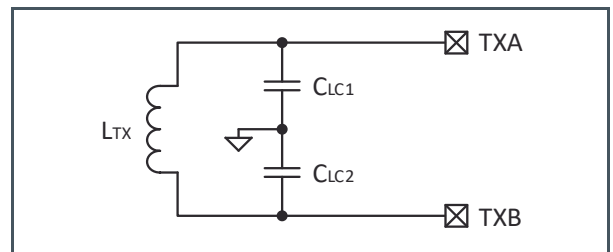
## 6.2 Oscillator

The AS5715A/AS5715R device and an external LC-tank form an LC-oscillator. The LC-tank consists of the components  $L_{TX}$ ,  $C_{LC1}$  and  $C_{LC2}$ . The minimum and maximum specified range of  $L_{TX}$  and  $C_{LC-TANK}$  must not be exceeded. Furthermore, the parasitic components of  $L_{TX}$  and  $C_{LC-TANK}$  must be within the specified range.

**Figure 13:**  
TX Resonator Signal



**Figure 14:**  
LC-Tank



**Equation 1:**

$$C_{LC-TANK} = \frac{C_{LC1} * C_{LC2}}{C_{LC1} + C_{LC2}}$$

**Equation 2:**

$$f_{TX} = \frac{1}{2 * \pi * \sqrt{L_{TX} * C_{LC-TANK}}}$$

The oscillation frequency of the LC-oscillator is  $f_{TX}$  and depends on the LC-tank. Equation 1 and Equation 2 show how to calculate  $f_{TX}$ . Note that  $f_{TX}$  has to be within the specified range.

## 6.3 Automatic Gain Control (AGC)

By default, the OTP register *AGC\_disable* is set to “0”, therefore the internal AGC algorithm is active and sets the gain for the two AM modulated RX signals (SIN and COS) as described in Figure 15. Depending on the coil system the AM modulated RX signal may have a high initial offset coming from the coil system. This offset may result in frequent gain changes over an electrical 360 deg rotation. EMC events that change voltages on the outputs may change the gain and may cause that the device does permanently change it's currently used gain until the next power on reset.

Alternatively, *AGC\_disable* can be set to “1”. Then the device permanently operates with the gain selected by the bits *AGC\_gain\_factor* <6:0>.

The startup procedure of the AGC is described in Figure 15. This startup procedure is executed each time after the device is powered on.

### **dis\_AGC\_boost**

When the *dis\_AGC\_boost* bit is “0” then the device does increase the gain until one of the differential outputs (SIN or COS) does reach a positive or negative voltage of  $V_{AGC\_REG\_H}/2$  and then does additionally increase the gain by 4 steps. The maximum possible gain is 109 steps.

### **dis\_AGC\_3dBred**

When the *dis\_AGC\_3dBred* bit is “0” then gain is reduced by 18 steps. The purpose of this reduction is that the gain does not change when the target is rotated after the startup procedure, assuming that the differential output signals have no offset and that the distance between the coil system and the target stays constant. Without this gain reduction the gain would change after the completion of the startup procedure when the target is rotated and when the target position before the startup is not 0, 90, 180 or 270 degrees. The minimum possible gain is 0 steps.

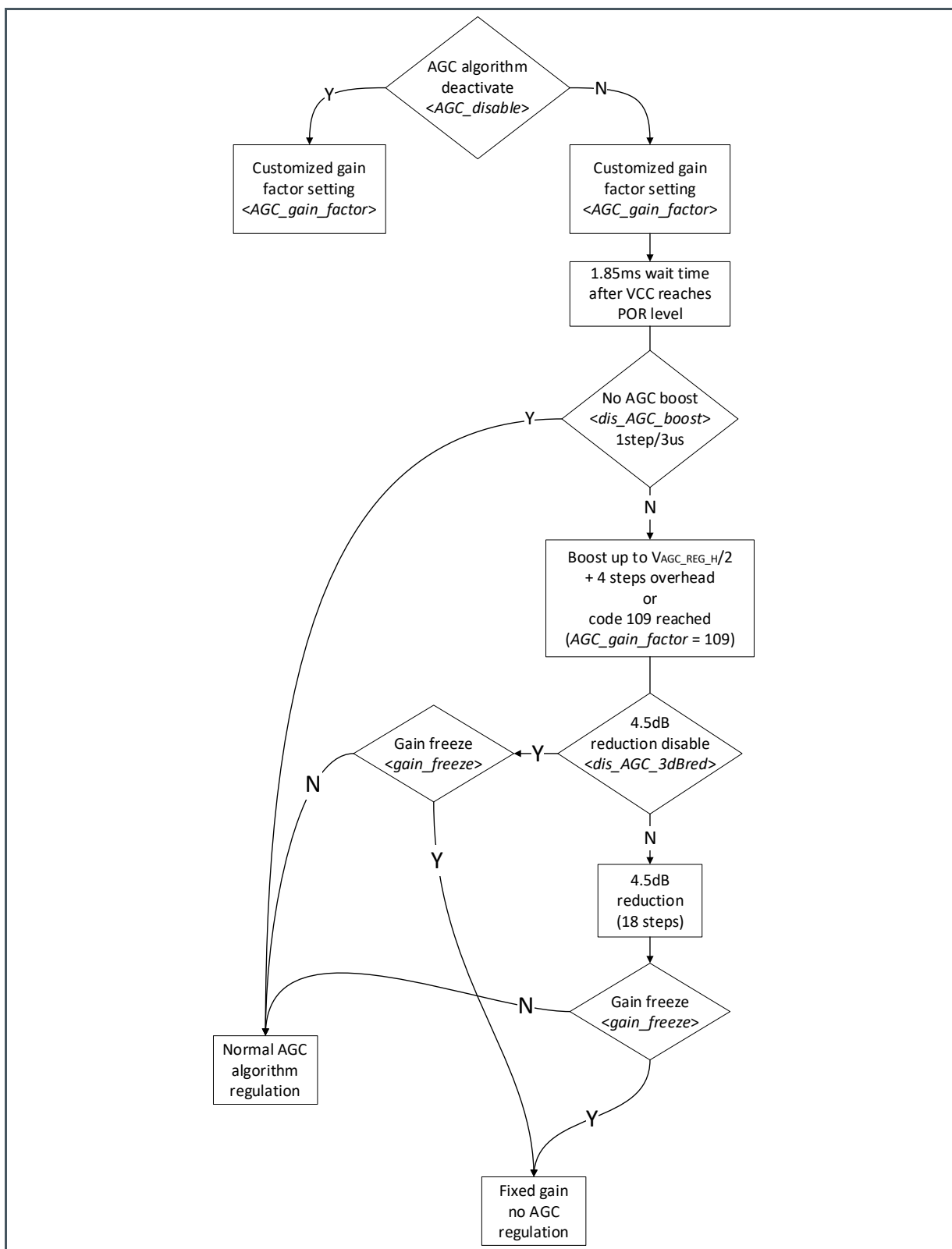
### **gain\_freeze**

When the gain freeze bit is “0” then the device does operate in fixed gain operation after the startup procedure. The gain will not change until the next startup.

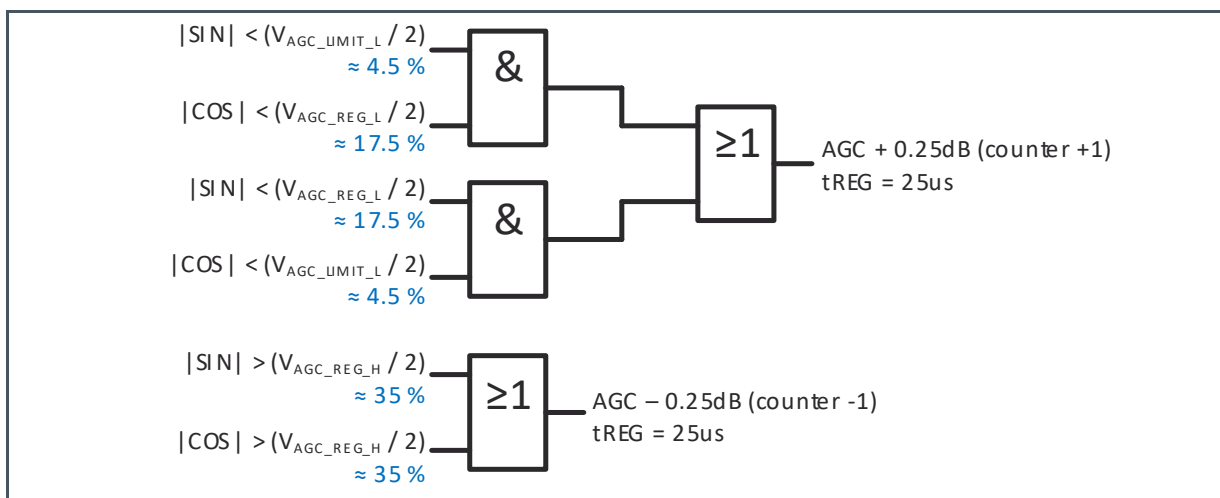
### **Normal AGC algorithm regulation**

The normal AGC algorithm regulation is described in Figure 16 and Figure 17. The logic gates decide by how many counts the gain will be increased or decreased. A logic “1” at the outputs of the gates causes a gain increase or decrease. A logic “0” at the outputs does not cause any gain change. The gain always changes for both channels together. The inputs of the gates are connected to comparators that compare the absolute value of the differential SIN and COS output signals to four different comparator levels. This comparator levels are derived from  $V_{AGC\_LIMIT\_L}$ ,  $V_{AGC\_REG\_L}$ ,  $V_{AGC\_REG\_H}$  and  $V_{AGC\_LIMIT\_H}$ . The regulation mode and step mode in Figure 16 and Figure 17 is executed periodically with the times  $t_{REG}$  and  $t_{LIMIT}$ .

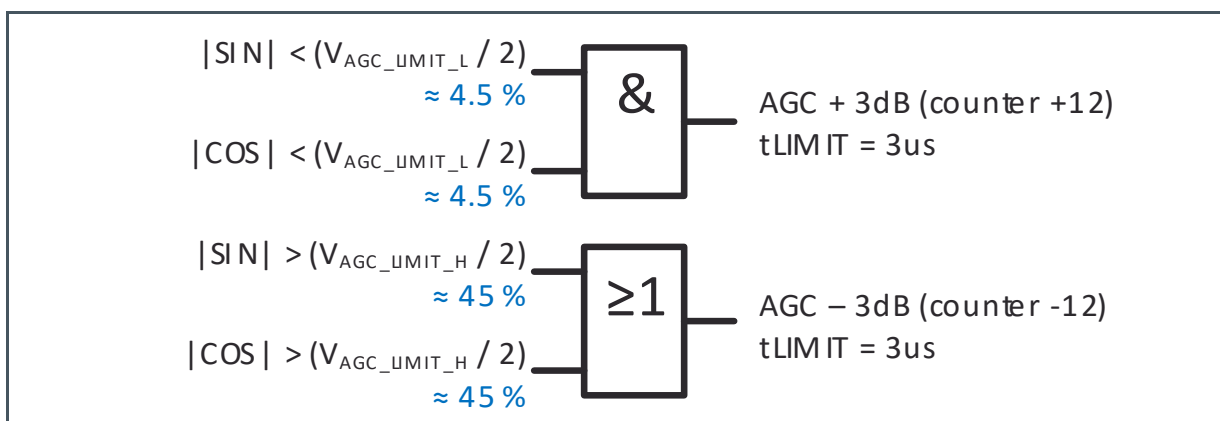
Figure 15:  
AGC Startup Procedure



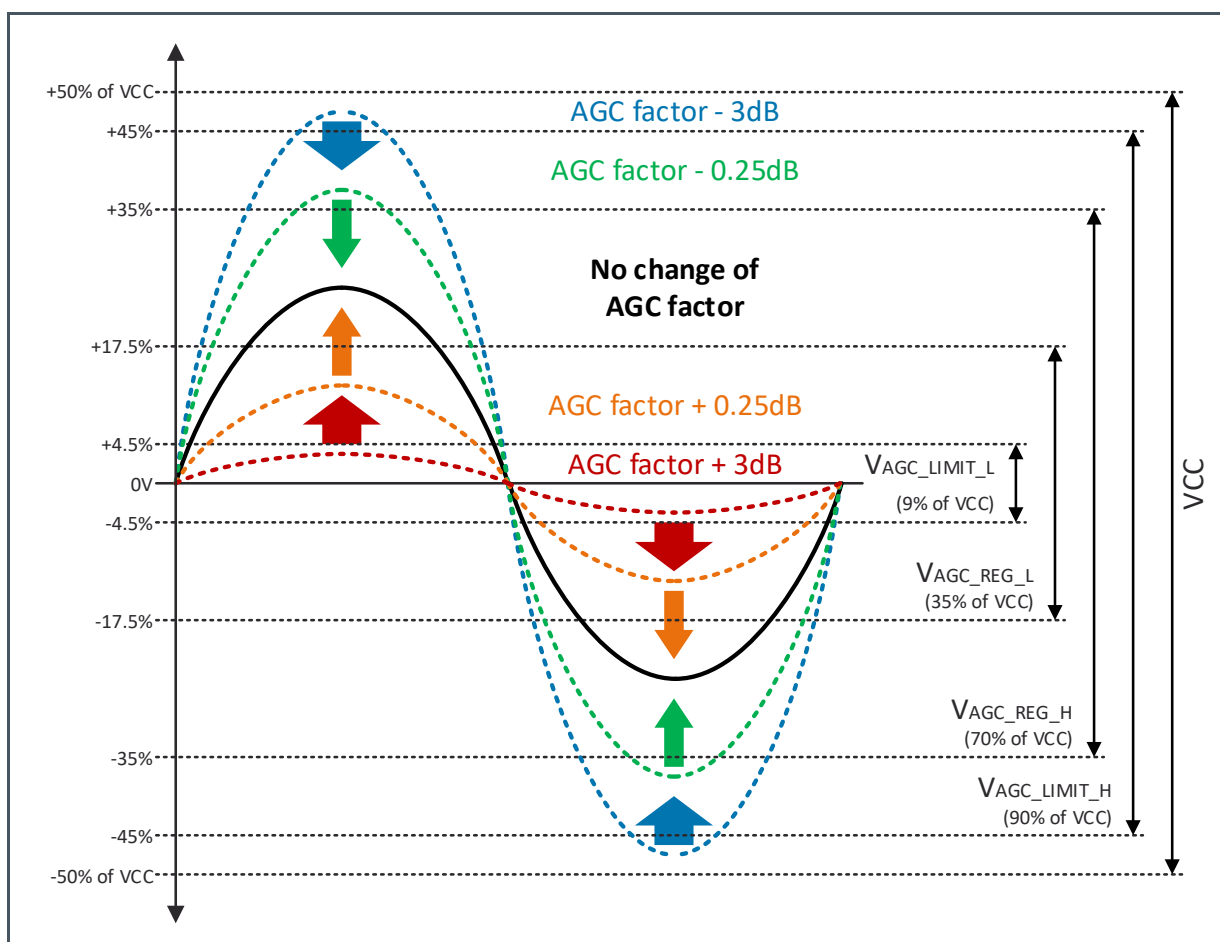
**Figure 16:**  
**Digital Implementation of Regulation Mode**



**Figure 17:**  
**Digital Implementation of Step Mode**



**Figure 18:**  
**AGC Regulation and Step Mode**



### Information

Whenever the AS5715R moves into safe state (valid for all safety mechanism initiations except the OTP signature check), the AGC gain freezes (assuming that the AGC algorithm is active) for this safe state condition duration.

As soon as the safe state condition expires and the AS5715R recovers into normal operation mode, the AGC gain unfreezes and it starts regulating with the same gain value as right before entering the safe state condition.

If the AGC algorithm is disabled, a well defined fixed gain factor must be chosen with respect to the expected maximum RX signal amplitude occurring in certain applications. If the gain factor is set too high, the RX input signal get over-amplified and starts to clip, which may lead into a wrong output signal.



## 6.4 Output

### 6.4.1 Output Signals

The differential SIN output signal is the voltage between the pins SIN+ and SIN-  
The differential COS output signal is the voltage between the pins COS+ and COS-

Figure 19 and Figure 20 show an example of the SIN+ and SIN- signal measured single ended (against GND):

- Red signal with peak2peak amplitude of 4.5% of VCC
- Yellow signal with peak2peak amplitude of 17.5% of VCC
- Green signal with peak2peak amplitude of 35% of VCC
- Blue signal with peak2peak amplitude of 45% of VCC

Beside this, the failure band is visible at the low and high side of the output voltage range.

**Figure 19:**  
**SIN+ Single-Ended Output Signal**

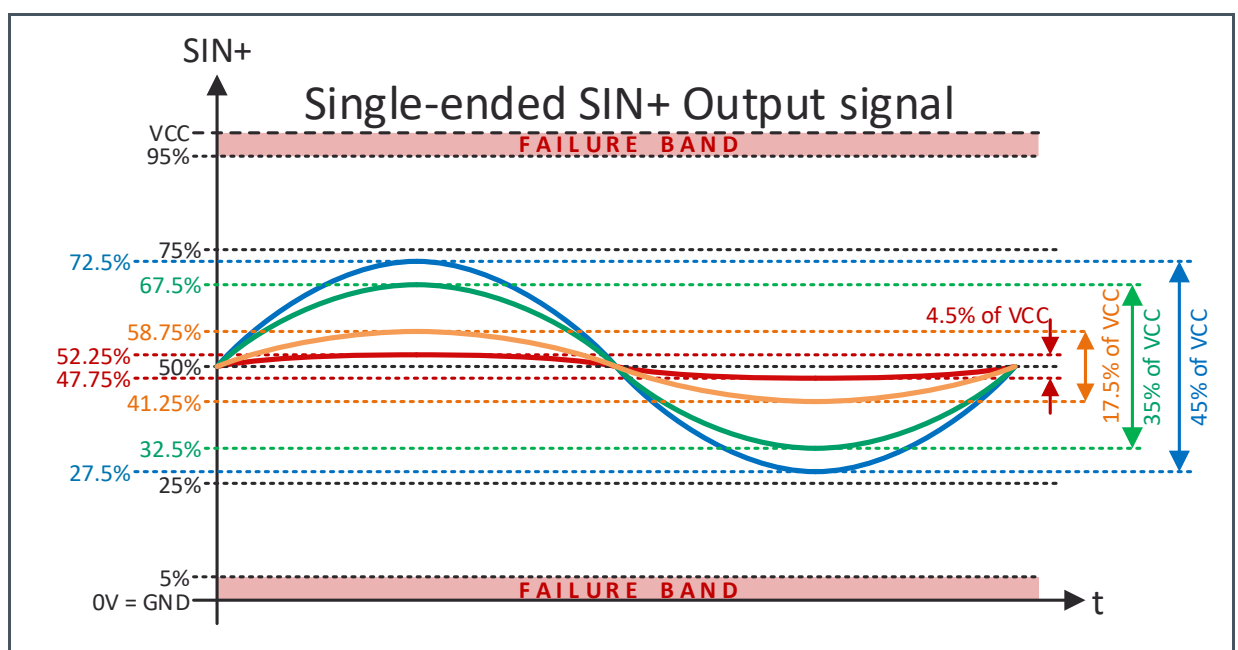
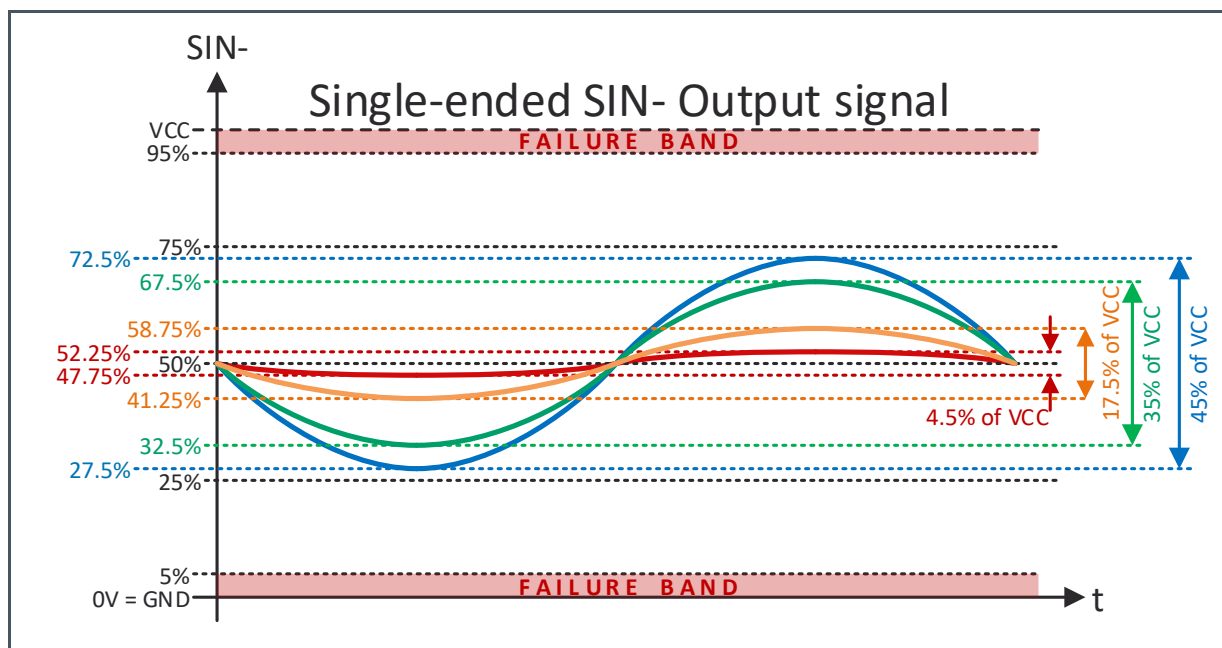


Figure 20:  
SIN- Single-Ended Output Signal

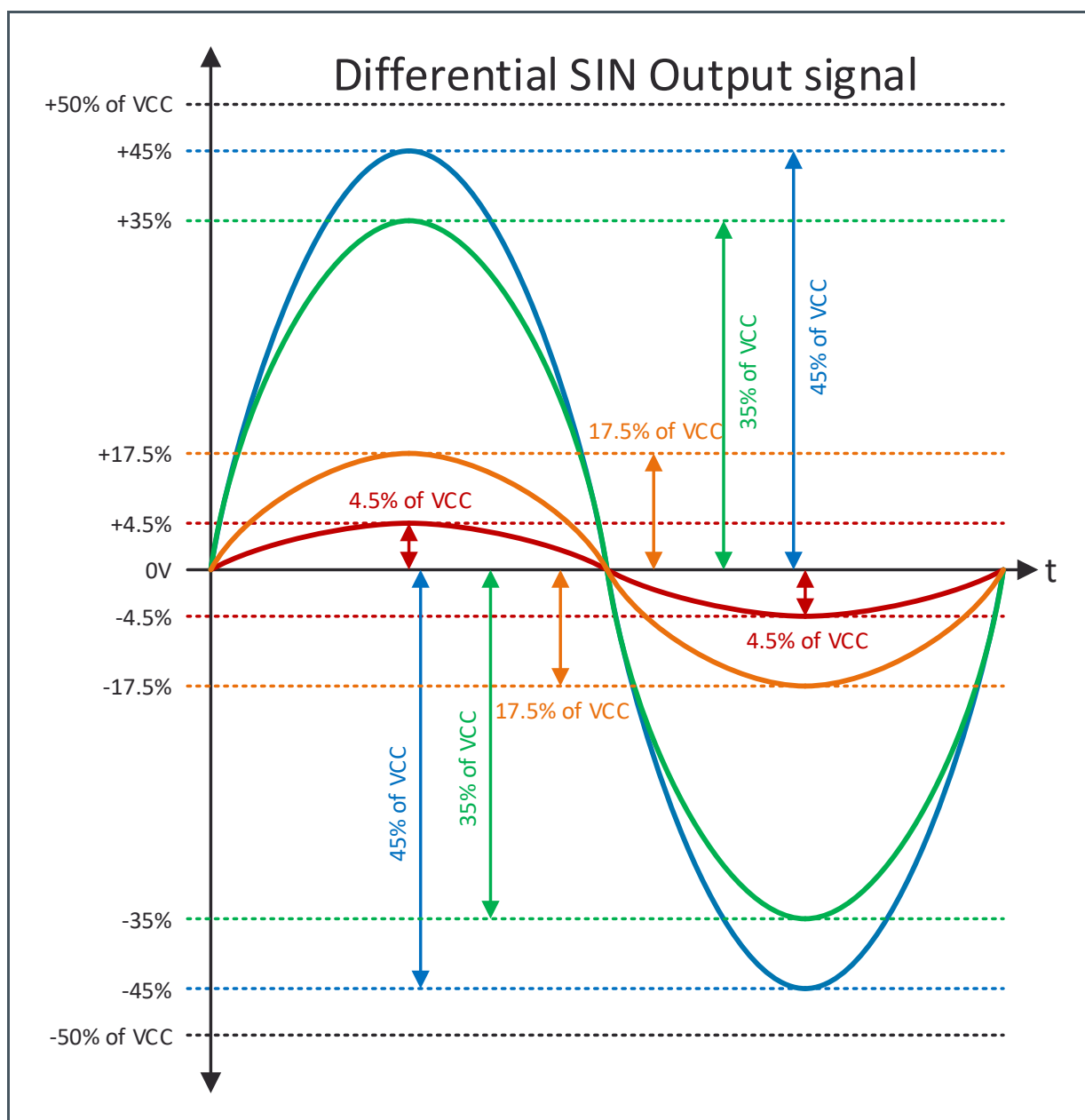


The corresponding differential SIN output signals are drawn in the figure below.

The differential signals are calculated from the single-ended signals (SIN+ minus SIN-):

- Red SIN signal → peak2peak amplitude of 9% of VCC →  $V_{AGC\_LIMIT\_L}$  threshold
- Yellow SIN signal → peak2peak amplitude of 35% of VCC →  $V_{AGC\_REG\_L}$  threshold
- Green SIN signal → peak2peak amplitude of 70% of VCC →  $V_{AGC\_REG\_H}$  threshold
- Blue SIN signal → peak2peak amplitude of 90% of VCC →  $V_{AGC\_LIMIT\_H}$  threshold

Figure 21:  
SIN Differential Output Signal



## 6.5 Diagnostic and Functional Safety

AS5715A/AS5715R can be used in safety critical applications. For this reason, AS5715A/AS5715R is developed as SEooC (Safety Element out of Context) according the ISO26262, with assumed safety goals and assumed ASIL level.

The assumption of use (AoU) and the embedded self-diagnostic, to achieve particular ASIL level in the application, are described in the AS5715A/AS5715R safety manual.

For additional information regarding the ISO26262 flow at ams OSRAM and the SEooC relevant documents (e.g. FMEDA, safety manual) please contact the technical support of ams OSRAM.

**Figure 22:**  
**Diagnostic Table**

| Symbol | Safety Mechanism                                      | Recoverable   | Safety State             |
|--------|---|---|--------------------------|
| SM1    | Watchdog failure<br>Oscillator frequency out of range | Yes,<br>if the frequency $f$ is again within the range of $f_{DET\_WD\_low} < f < f_{DET\_WD\_high}$ .      | Safe State Definition 1  |
| SM2    | Receive coil open detection                           | Yes,<br>if coil open is resolved  | Safe State Definition 2  |
| SM3    | VCC overvoltage detection                             | Yes,<br>if VCC is below the specified threshold. (see Figure 12)  | Safe State Definition 3  |
| SM4    | VCC undervoltage detection                            | Yes,<br>if VCC is above the specified threshold. (see Figure 12)  | Safe State Definition 4  |
| SM5    | V <sub>LDO</sub> overvoltage detection                | Yes,<br>if V <sub>LDO</sub> returns to the specified range  | Safe State Definition 5  |
| SM6    | V <sub>LDO</sub> undervoltage detection               | Yes,<br>if V <sub>LDO</sub> returns to the specified range  | Safe State Definition 6  |
| SM7    | OTP Signature check                                   | No,<br>the device stays in failure band until the OTP content is correct and a power on reset is performed. | Safe State Definition 7  |
| SM8    | Output Short circuit detection                        | Yes,<br>if short is resolved  | Safe State Definition 8  |
| SM9    | VCC Reverse polarity                                  | Yes,<br>if polarity is correct.   | Safe State Definition 9  |
| SM10   | Output signal too low                                 | Yes,<br>if output signal amplitude is getting increased   | Safe State Definition 10 |
| SM11   | Output signal too high                                | Yes,<br>if output signal amplitude is getting decreased   | Safe State Definition 11 |

**Figure 23:**  
**Safe State Definition**

| Symbol               | Safe State Definition | signaling_disable | SIN+                  | SIN-   | COS+   | COS-   |
|----------------------|-----------------------|-------------------|-----------------------|--------|--------|--------|
| SSD1                 | Safe State for SM1    | 0<br>1            | PWM (0:100)<br>high-Z | high-Z | high-Z | high-Z |
| SSD2                 | Safe State for SM2    | 0<br>1            | PWM (20:80)<br>high-Z | high-Z | high-Z | high-Z |
| SSD3                 | Safe State for SM3    | 0<br>1            | high-Z                | high-Z | high-Z | high-Z |
| SSD4                 | Safe State for SM4    | 0<br>1            | PWM (40:60)<br>high-Z | high-Z | high-Z | high-Z |
| SSD5                 | Safe State for SM5    | 0<br>1            | high-Z                | high-Z | high-Z | high-Z |
| SSD6                 | Safe State for SM6    | 0<br>1            | PWM (60:40)<br>high-Z | high-Z | high-Z | high-Z |
| SSD7                 | Safe State for SM7    | 0<br>1            | PWM (70:30)<br>high-Z | high-Z | high-Z | high-Z |
| SSD8                 | Safe State for SM8    | 0<br>1            | high-Z                | high-Z | high-Z | high-Z |
| SSD9                 | Safe State for SM9    | 0<br>1            | high-Z                | high-Z | high-Z | high-Z |
| SSD10 <sup>(1)</sup> | Safe State for SM10   | 0<br>1            | PWM (80:20)<br>high-Z | high-Z | high-Z | high-Z |
| SSD11 <sup>(1)</sup> | Safe State for SM11   | 0<br>1            | PWM (90:10)<br>high-Z | high-Z | high-Z | high-Z |

<sup>(1)</sup> Enable/disable by customer OTP bit setting.

The PWM frequency is 500 Hz. The PWM voltage may not be rectangular, depending on the used pullup resistor and output capacitor.

E.g. PWM (20:80) stands for 20% high level and 80% low level.

## 6.6 I<sup>2</sup>C Interface and Communication Procedure

The AS5715R will start up in operational mode after powering up. In operational mode the 4 analog outputs of the device are operational.

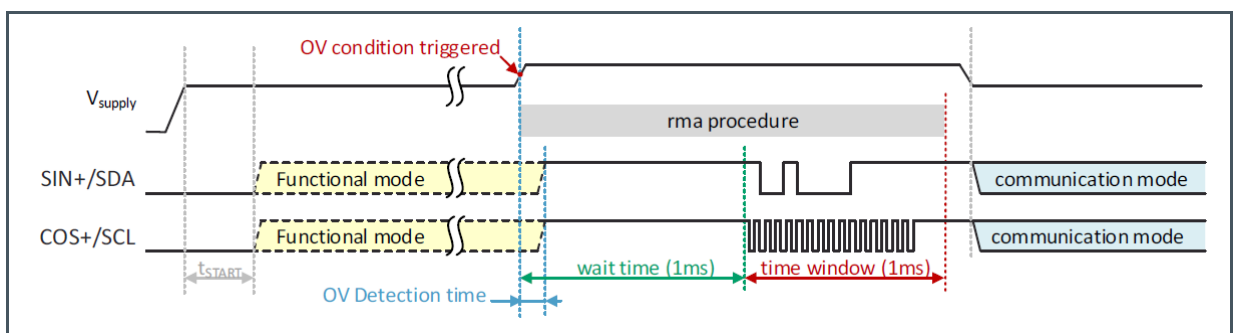
The AS5715R features an OTP (One Time Programmable) memory. This memory can be used to program custom settings. The OTP can be programmed over an I<sup>2</sup>C interface which is applicable at the pins SIN+/SDA and COS+/SCL. The 7-bit slave address of the AS5715R is 40h.

To activate the I<sup>2</sup>C interface, the so called customer rma procedure is performed. The customer rma procedure allows to switch the analog outputs into I<sup>2</sup>C mode in order to allow programming over I<sup>2</sup>C. To switch the outputs back into operational mode without burning the OTP, the pass2func command can be used.

### 6.6.1 Customer rma Procedure

1. On the VCC pin, an overvoltage condition must be applied by supplying with a voltage between 5.95 V and 20 V.
2. The OV detection takes ~50  $\mu$ s followed by a 1 ms wait time. After this, a 1 ms window is open to execute the customer rma procedure.
3. To execute the customer rma procedure it is necessary to apply 2 pulses (= 2 x rising edge) on SIN+/SDA and independent from that, 16 pulses (= 16 x rising edge) on COS+/SCL during the rma window. The pulses must be applied with a frequency <1 MHz.
4. After this, the I<sup>2</sup>C port is open and the VCC supply voltage must be reduced to the operating voltage range before I<sup>2</sup>C communication is possible.

**Figure 24:**  
**Customer rma Procedure**



## 6.6.2 pass2func Command

The pass2func command is useful to check the effect of changed memory settings before burning them into the OTP. The pass2func switches the device from I<sup>2</sup>C mode into functional mode without the need to perform a power on reset or burning the OTP.

If a register bit gets changed, it is important also to adjust the signature byte as well. Even if a correct signature is written, the signature error is triggered, because the error is latched. To clean the signature error it's necessary to write dsp\_rst before performing a pass2func command.

The pass2func is executed when the register **PASS2FUNCT** (address f1h) is written with the value 01010011b (53h). After the pass2func command, the I<sup>2</sup>C interface is disabled and the only way to enable again the communication mode is an execution of the customer rma procedure.

## 6.6.3 Customer Signature Calculation

After the desired bit settings of the customer OTP registers **P2RAM\_BYTE\_13**, **P2RAM\_BYTE\_14** and **P2RAM\_BYTE\_15**, the correct setting of the customer signature bits must be applied into register **P2RAM\_BYTE\_16**. The OTP of AS5715R uses a BIST technique with Multiple Input Signature Register circuits. To activate this Built-In-Self-Test, a calculation of the signature byte is necessary which has to be stored in the OTP during programming. For calculating the signature byte, the content of the whole memory has to be read out. Out of this information, the following calculation has to be done.

```
@content =($byte0, $byte1, $byte2, $byte3, $byte4, $byte5, $byte6, $byte7, $byte8, $byte9, $byte10, $byte11, $byte12, $byte13, $byte14, $byte15);
```

```
$misr = 0;
for($i=12; $i< 15; $i++) {
    $misr_shift = ($misr<<1);
    $misr_xor = ($misr_shift ^ $content[$i]) & 0xFF;
    $misr_msb = $misr/(128);
    if ($misr_msb eq 0) {
        $misr = $misr_xor;
    }
    else
    {
        $misr = ($misr_xor ^ 29) & 0xFF;
    }
}
```

## 6.6.4 Burning Procedure for Customer OTP Section

Before to activate the burning procedure of the customer OTP section, the customer has to write first the unlock command 01h to the register **P2RAM\_CONTROL** (address 03h), otherwise the burning function is locked. Now the OTP is ready for burning.

The BURN command has to be triggered by writing 08h to the register **P2RAM\_CONTROL**. The status of the burning procedure can be seen by polling the BURN bit. During burn operation it stays high and get released to 0 after the burning procedure has finished. The content of the register **P2RAM\_CONTROL** will be 09h during burning and 01h when burning procedure is finished.

To check the quality of the burned fuses, right after the burning process, the whole customer OTP section (register **P2RAM\_BYTE\_13** up to register **P2RAM\_BYTE\_16**) should be set to 00h. Using the LOAD operation by writing 04h to the register **P2RAM\_CONTROL** will load the content of the burned fuses into the customer OTP section and the correct content can be checked.

The same routine has to be done with the GLOAD command!  
Set the whole customer OTP section (register **P2RAM\_BYTE\_13** up to register **P2RAM\_BYTE\_16**) to 00h again. Use the GLOAD + LOAD operation by writing 44h to the register **P2RAM\_CONTROL** and this will load again the content of the burned fuses into the customer OTP section and check, if the content is correct.



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### Information

GLOAD Test:

Restricted to temperature range: 25 °C ± 20 °C

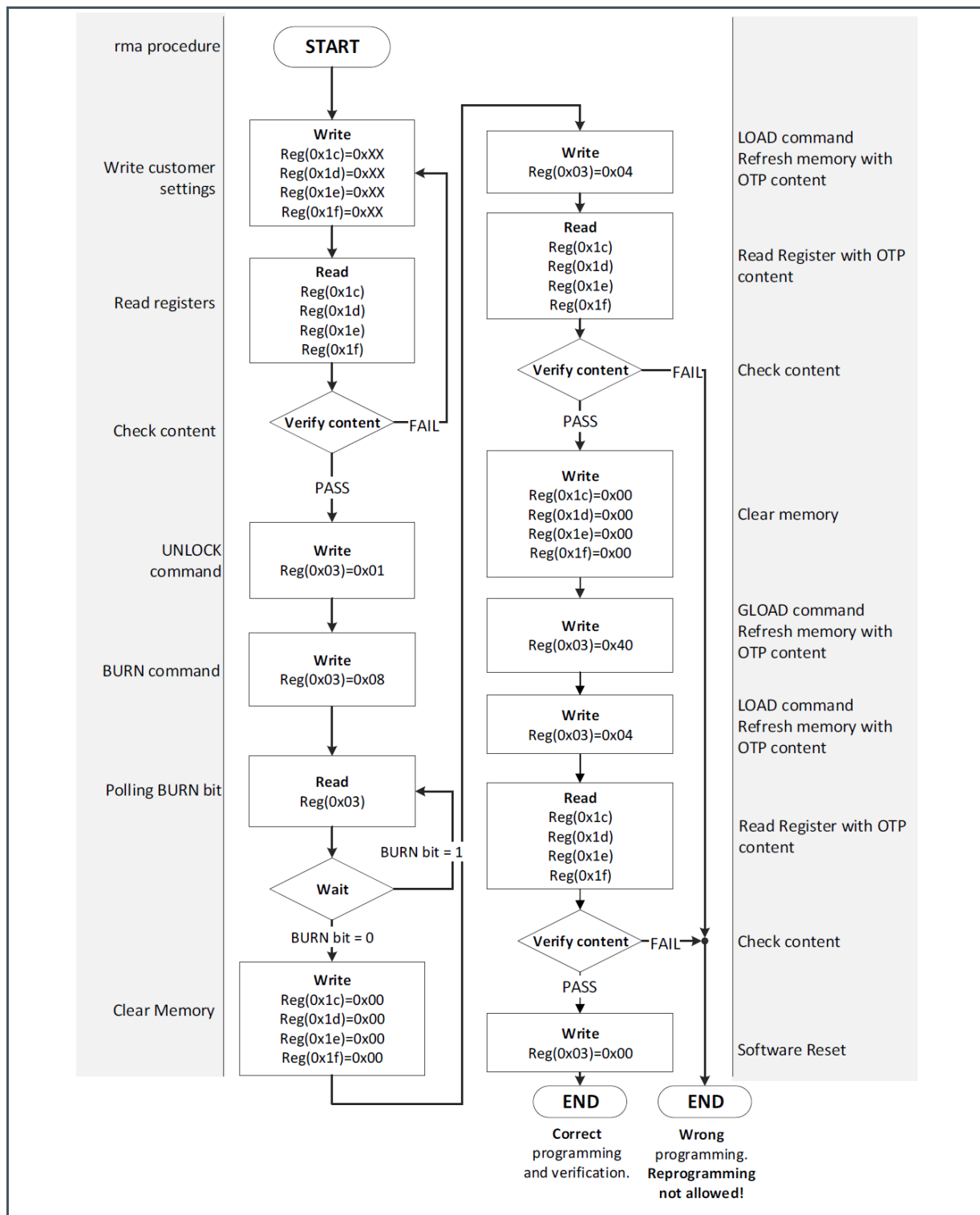
Right after the programming procedure (max. 1 hour with same conditions 25 °C ± 20 °C), same VCC voltage. The GLOAD test is only for the verification of the burned OTP fuses during the programming sequence. The use of GLOAD in other cases is not allowed.

---



## 6.6.5 Programming Flowchart

Figure 25:  
Programming Flowchart



# 7 Register Description

## 7.1 Register Overview

Figure 26:  
Register Overview

| Addr          | Name                 | <D7>                     | <D6>                       | <D5>                    | <D4>                      | <D3>                     | <D2>                      | <D1>                     | <D0>                     |
|---------------|----------------------|--------------------------|----------------------------|-------------------------|---------------------------|--------------------------|---------------------------|--------------------------|--------------------------|
| OTP Registers |                      |                          |                            |                         |                           |                          |                           |                          |                          |
| 1h            | <b>ERROR</b>         | <7><br>VLDO_undervoltage | <6><br>VLDO_overservoltage | <5><br>VCC_undervoltage | <4><br>VCC_overservoltage | <3><br>coil_sc_break     | <2><br>cust_signature_err | <1><br>ams_signature_err | <0><br>watchdog_failure  |
| 2h            | <b>RESET</b>         |                          |                            |                         |                           |                          |                           |                          | dsp_rst                  |
| 3h            | <b>P2RAM_CONTROL</b> |                          |                            |                         |                           | <3> BURN bit             |                           |                          |                          |
| 10h           | <b>CHIPID0</b>       |                          |                            |                         | <7:0> Chip_ID             |                          |                           |                          |                          |
| 11h           | <b>CHIPID1</b>       |                          |                            |                         | <15:8> Chip_ID            |                          |                           |                          |                          |
| 12h           | <b>CHIPID2</b>       |                          |                            |                         | <23:16> Chip_ID           |                          |                           |                          |                          |
| 1ch           | <b>P2RAM_BYTE_13</b> | <7><br>cust_spare1       | <6><br>short_n_dis         | <5><br>short_p_dis      | <4><br>AGC_cmp_high_thr   | <3><br>gain_freeze       | <2><br>dis_AGC_3dBred     | <1><br>dis_AGC_boost     | <0><br>en_out_startup    |
| 1dh           | <b>P2RAM_BYTE_14</b> | <7><br>signaling_disable | <6><br>gain_check_disable  | <5><br>LC_wide_range    | <4><br>vdd3v3_ov_disable  | <3><br>vdd3v3_uv_disable | <2><br>vcc_ov_disable     | <1><br>vcc_uv_disable    | <0><br>SC_filter_disable |
| 1eh           | <b>P2RAM_BYTE_15</b> | <7><br>AGC_disable       |                            |                         |                           | <6:0><br>AGC_gain_factor |                           |                          |                          |
| 1fh           | <b>P2RAM_BYTE_16</b> |                          |                            |                         | <7:0><br>cust_signature   |                          |                           |                          |                          |
| f2h           | <b>AGC_VALUE</b>     | <7><br>gain_error        |                            |                         | <6:0> agc_cnt_value       |                          |                           |                          |                          |

## 7.2 Detailed Register Description

### 7.2.1 P2RAM\_BYTE\_13 Register (Address 1ch)

| Addr: 1ch |                         | P2RAM_BYTE_13 |        |  |
|-----------|-------------------------|---------------|--------|--|
| Bit       | Bit Name                | Default       | Access | Bit Description  |
| 7         | <i>cust_spare1</i>      | b0            | RW     | Customer spare bit   |
| 6         | <i>short_n_dis</i>      | b0            | RW     | Disables the output short circuit monitoring to GND<br>0 : Active<br>1 : Inactive  |
| 5         | <i>short_p_dis</i>      | b0            | RW     | Disables the output short circuit monitoring to VCC<br>0 : Active<br>1 : Inactive  |
| 4         | <i>AGC_cmp_high_thr</i> | b0            | RW     | Sets all AGC threshold to a 30% higher value<br>0 : Normal AGC comparator thresholds<br>1 : 30% higher AGC comparator thresholds   |
| 3         | <i>gain_freeze</i>      | b0            | RW     | Allows to freeze the AGC gain factor after the boost to the $V_{AGC\_REG\_H}$ threshold (depends on 3dB reduction setting)<br>0 : No gain freeze<br>1 : Gain freeze after boost (if <i>dis_AGC_3dBred</i> is set) or after boost + 3dB reduction (if <i>dis_AGC_3dBred</i> is not set) |
| 2         | <i>dis_AGC_3dBred</i>   | b0            | RW     | Disables the AGC gain factor reduction of 3dB after the boost to the $V_{AGC\_REG\_H}$ threshold<br>0 : 3dB gain reduction<br>1 : No gain reduction  |
| 1         | <i>dis_AGC_boost</i>    | b0            | RW     | Disables the automatic AGC incrementing (boost) after startup up the 70% threshold or code 109<br>0 : AGC boost enabled<br>1 : AGC boost disabled  |
| 0         | <i>en_out_startup</i>   | b0            | RW     | Enables the analog SIN/COS outputs also during startup phase<br>0 : SIN/COS outputs are disabled during startup phase<br>1 : SIN/COS outputs are enabled during startup phase  |

### 7.2.2 P2RAM\_BYTE\_14 Register (Address 1dh)

| Addr: 1dh |                           | P2RAM_BYTE_14 |        |   |
|-----------|---------------------------|---------------|--------|---|
| Bit       | Bit Name                  | Default       | Access | Bit Description   |
| 7         | <i>signaling_disable</i>  | b0            | RW     | Disables the signaling of failure type on analog outputs<br>0 : Failure signaling on outputs enabled<br>1 : Failure signaling on outputs disabled |
| 6         | <i>gain_check_disable</i> | b0            | RW     | Disables the output signal amplitude monitoring (signal too high/too low)<br>0 : Output signal amplitude monitoring enabled                       |

| Addr: 1dh |                          | P2RAM_BYTE_14 |        |  |
|-----------|--------------------------|---------------|--------|--|
| Bit       | Bit Name                 | Default       | Access | Bit Description  |
|           |                          |               |        | 1 : Output signal amplitude monitoring disabled  |
| 5         | <i>LC_wide_range</i>     | b0            | RW     | Set a wider range for LC frequency check in watchdog<br>0 : LC check counter range (26/55)<br>1 : LC check counter range (26/75) |
| 4         | <i>vdd3v3_ov_disable</i> | b0            | RW     | Disables the 3.3 V regulator overvoltage flag<br>0 : 3.3 V OV monitoring enabled<br>1 : 3.3 V OV monitoring disabled             |
| 3         | <i>vdd3v3_uv_disable</i> | b0            | RW     | Disables the 3.3 V regulator undervoltage flag<br>0 : 3.3 V UV monitoring enabled<br>1 : 3.3 V UV monitoring disabled            |
| 2         | <i>vcc_ov_disable</i>    | b0            | RW     | Disables the VCC overvoltage flag<br>0 : VCC OV monitoring enabled<br>1 : VCC OV monitoring disabled                             |
| 1         | <i>vcc_uv_disable</i>    | b0            | RW     | Disables the VCC undervoltage flag<br>0 : VCC UV monitoring enabled<br>1 : VCC UV monitoring disabled                            |
| 0         | <i>SC_filter_disable</i> | b0            | RW     | Disables the SC filter in RX chain<br>0 : SC filter is enabled<br>1 : SC filter is disabled                                      |

### 7.2.3 P2RAM\_BYTE\_15 Register (Address 1eh)

| Addr: 1eh |                 | P2RAM_BYTE_15 |        |  |
|-----------|-----------------|---------------|--------|--|
| Bit       | Bit Name        | Default       | Access | Bit Description  |
| 7         | AGC_disable     | b0            | RW     | Disables the AGC algorithm<br>0 : AGC algorithm is enabled<br>1 : AGC algorithm is disabled  |
| 6:0       | AGC_gain_factor | b000 0000     | RW     | Defines the fixed gain factor if <i>AGC_disable</i> = 1 or defines the default gain factor (after startup or reset) if <i>AGC_disable</i> = 0<br>0 : 25dB<br>...<br>109 : 52.25 dB<br>110 – 127 : not applicable<br>$AGC\_gain\_factor\_dB = AGC\_gain\_factor * AGC_{STEP\_REG} + 25$ |

### 7.2.4 P2RAM\_BYTE\_16 Register (Address 1fh)

| Addr: 1fh |                | P2RAM_BYTE_16 |        |   |
|-----------|----------------|---------------|--------|---|
| Bit       | Bit Name       | Default       | Access | Bit Description                             |
| 7:0       | cust_signature | b0000 0000    | RW     | Signature byte for the customer OTP section |

### 7.2.5 AGC\_VALUE Register (Address f2h)

| Addr: f2h |               | AGC_VALUE |        |   |
|-----------|---------------|-----------|--------|---|
| Bit       | Bit Name      | Default   | Access | Bit Description   |
| 7         | gain_error    | b0        | RO     | Gain error flag triggered by AGC saturated + too low or too high signal |
| 6:0       | agc_cnt_value |           | RO     | Read current gain value (for evaluation purposes only)                  |

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## 8 Functional Safety

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### 8.1 Safety Manual

The Safety Manual, available upon request, contains all the necessary information for the system integrator, to integrate AS5715A/AS5715R in a safety related item.

The sensor is supporting the ISO26262 as Safety Element out of Context (SEooC).

The Safety Manual includes the following information:

- Product development lifecycle
- Description of the technical safety concept on system level
- Detailed information of Assumption of Use of the element with respect to its intended use, which includes:
  - System Safe State information
  - Fault Tolerant Time Interval
  - Coverage information

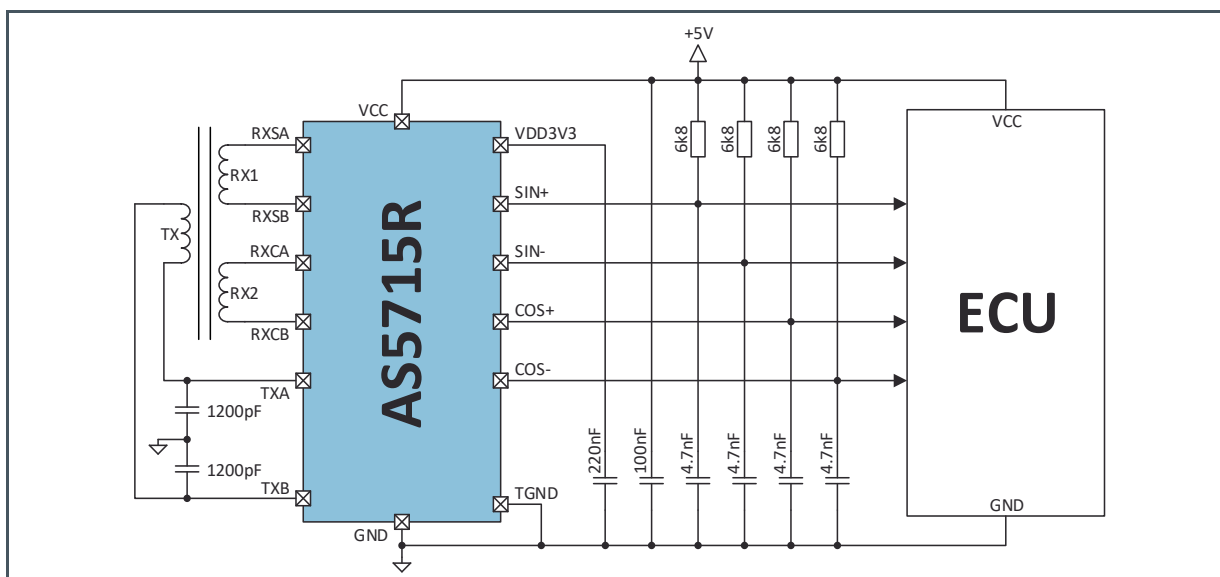
As part of the Safety Manual, the Verification and Safety Analysis Report includes following information:

- HW architectural metric results (Single Point Fault Metric)
- Description of verifications based on the ISO26262
- Detailed FMEDA

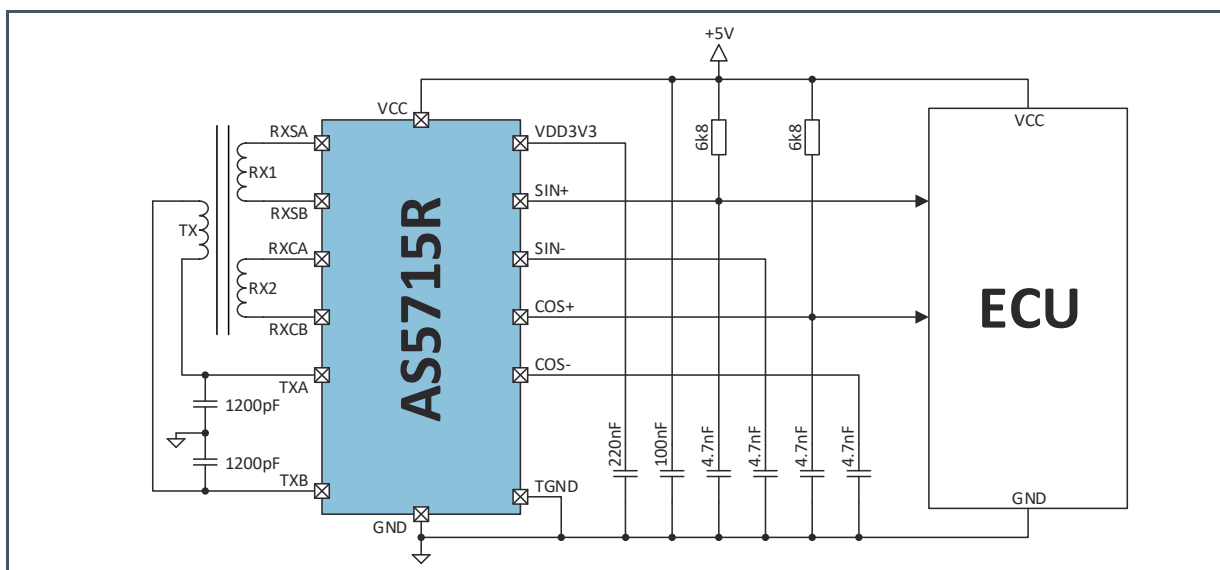
## 9 Application Information

### 9.1 Typical Application Circuits

**Figure 27:**  
Typical Differential Output Application for 5 V VCC Supply System



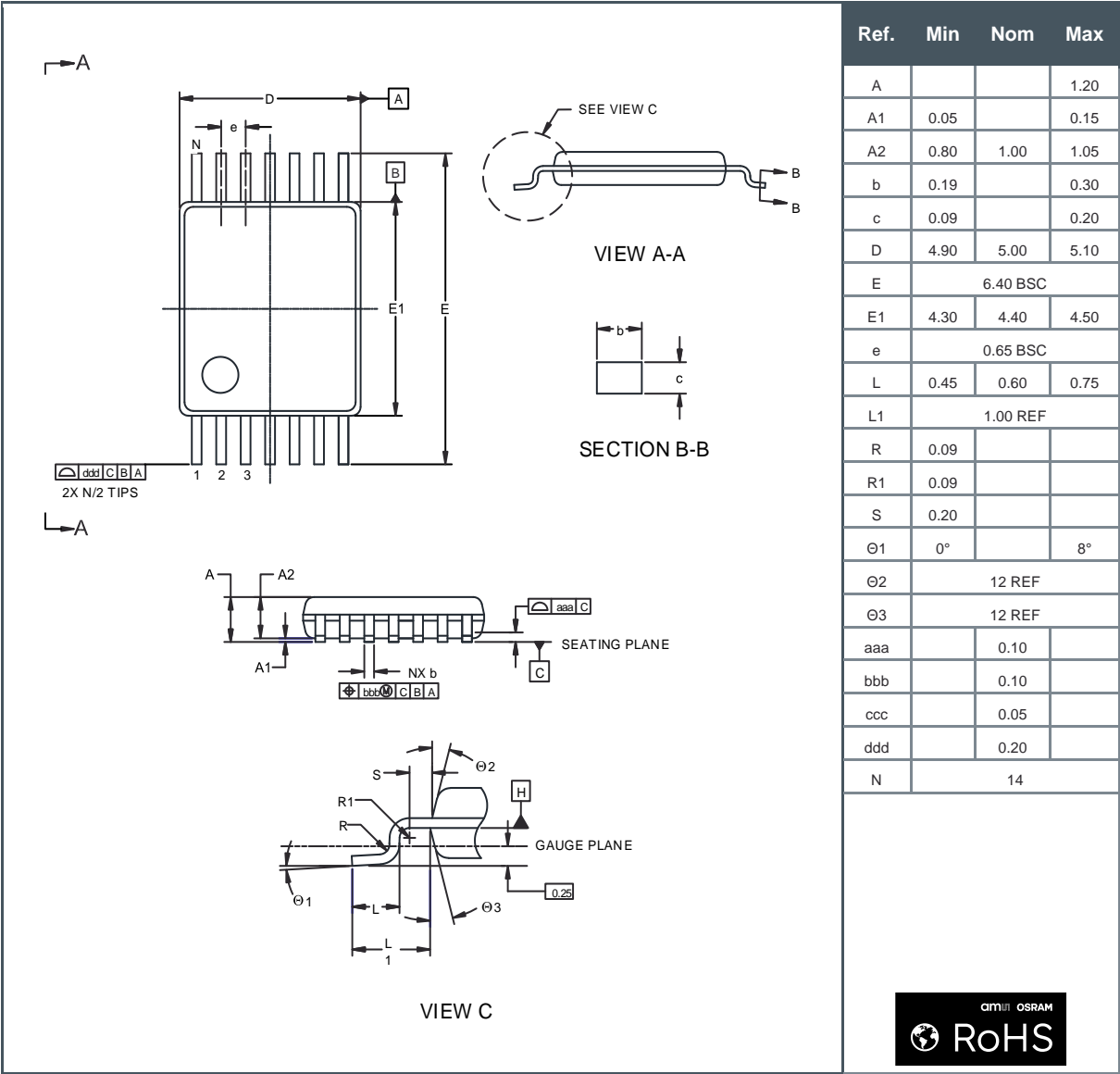
**Figure 28:**  
Typical Single Ended Output Application for 5 V VCC Supply System



(1) The accuracy specifications in this datasheet are valid for the Differential Output Application only.

# 10 Package Drawings & Markings

Figure 29:  
TSSOP14 Package Outline Drawing



- (1) All dimensions are in millimeters. Angles in degrees.  
(2) Dimensioning and tolerancing conform to ASME Y14.5-2009.  
(3) N is the total number of terminals.



Figure 30:  
TSSOP14 Package Marking/Code for AS5715R

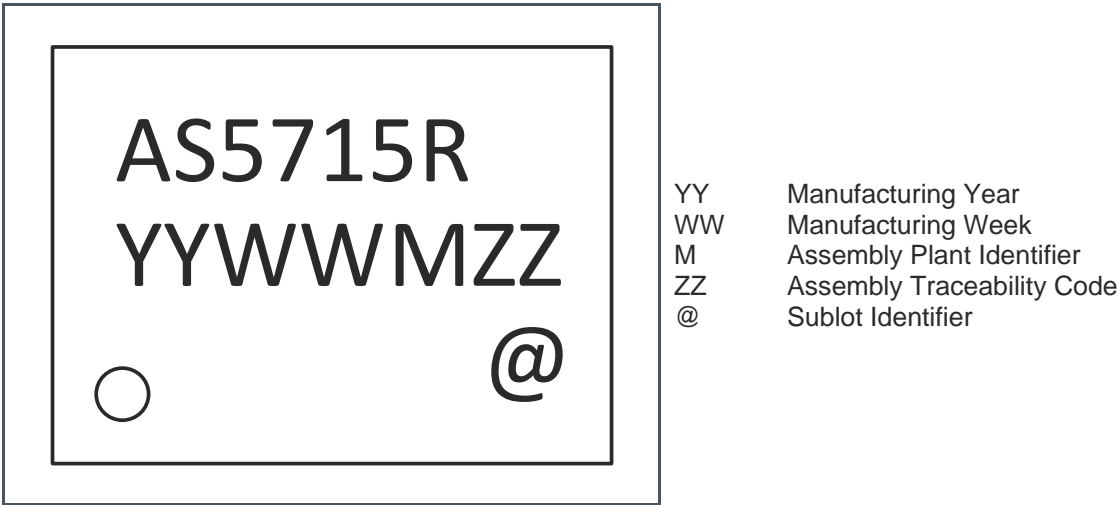
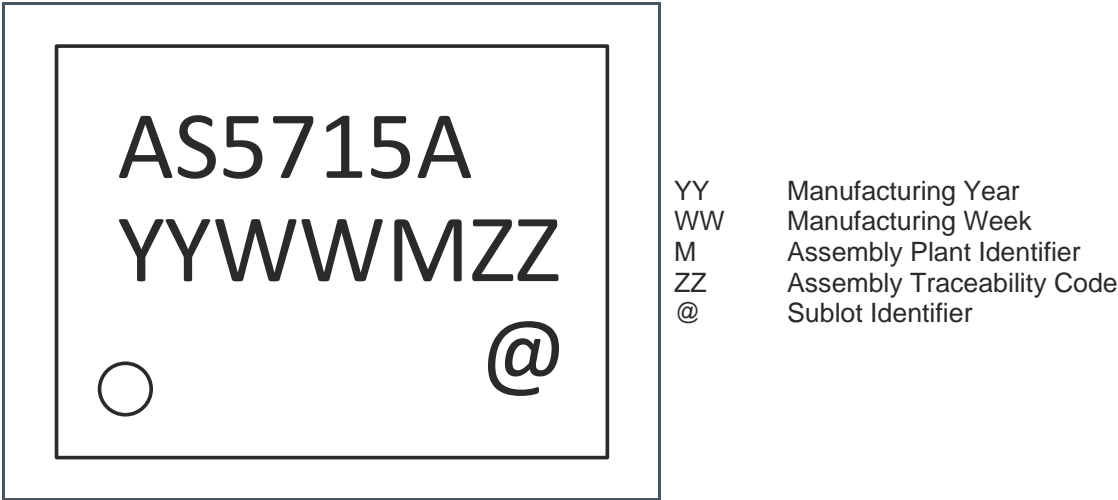


Figure 31:  
TSSOP14 Package Marking/Code for AS5715A



# 11 Revision Information

| Document Status       | Product Status  | Definition  |
|-----------------------|-----------------|---|
| Product Preview       | Pre-Development | Information in this datasheet is based on product ideas in the planning phase of development. All specifications are design goals without any warranty and are subject to change without notice   |
| Preliminary Datasheet | Pre-Production  | Information in this datasheet is based on products in the design, validation or qualification phase of development. The performance and parameters shown in this document are preliminary without any warranty and are subject to change without notice |
| Datasheet             | Production      | Information in this datasheet is based on products in ramp-up to full production or full production which conform to specifications in accordance with the terms of ams-OSRAM AG standard warranty as given in the General Terms of Trade               |

## Other Definitions

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### Short Datasheet:

A short datasheet is intended for quick reference only, it is an extract from a full datasheet with the same product number(s) and title. For detailed and full information always see the relevant full datasheet. In case of any inconsistency or conflict with the short datasheet, the full datasheet shall prevail.

| Changes from previous version to current revision v5-00                    | Page |
|--|------|
| Changed lower limit for VDD3V3OVTH   | 15   |
| Changed lower and upper limits for VDD3V3OVL                               | 15   |
| Changed lower limit for VDD3V3UVTH   | 15   |
| Changed upper limit for VDD3V3UVTL   | 15   |
| Changed upper limit for VLDO   | 16   |
| Chapter 6.6, added information for the default slave address of the device | 29   |

- Page and figure numbers for the previous version may differ from page and figure numbers in the current revision.
- Correction of typographical errors is not explicitly mentioned.

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## Headquarters

ams-OSRAM AG  
Tobelbader Strasse 30  
8141 Premstaetten  
Austria, Europe  
Tel: +43 (0) 3136 500 0

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